

SKiiP 962 GB 060 - 350 WT/FT

Absolute Maximum Ratings		Values	Units
Symbol	Conditions ¹⁾		
IGBT & Inverse Diode			
V _{CES}		600	V
V _{CC} ¹⁰⁾	Operating DC link voltage	400	V
I _C	T _{heatsink} = 25 °C	900	A
I _{CM}	T _{heatsink} = 25 °C; t _p < 1 ms	1800	A
T _J ³⁾	IGBT & Diode	- 40 ... + 150	°C
V _{isol} ⁴⁾	AC, 1 min.	2500	V
I _F	T _{heatsink} = 25 °C	900	A
I _{FM}	T _{heatsink} = 25 °C; t _p < 1 ms	1800	A
I _{FSM}	t _p = 10 ms; sin.; T _J = 150 °C	6480	A
I ² t (Diode)	t _p = 10 ms; T _J = 150 °C	210	kA ² s
Driver			
V _{S1}	Stabilized power supply	18	V
V _{S2} ⁹⁾	Nonstabilized power supply	30	V
dv/dt	Primary to second. side	75	kV/μs
T _{op} , T _{stg}	Operating / stor. temperature (version FT)	- 25(0) ... + 85(70)	°C

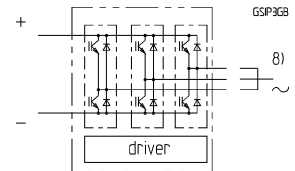
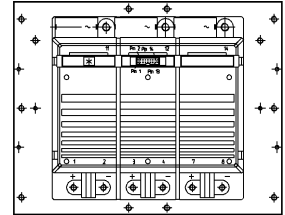
Characteristics		min.	typ.	max.	Units
Symbol	Conditions ¹⁾				
V _{(BR)CES}	Driver without power supply	≥ V _{CES}	-	-	V
I _{CES}	V _{GE} = 0 } T _J = 25 °C V _{CE} = V _{CES} } T _J = 125 °C	-	1,2	-	mA
V _{CEsat}	I _C = 675 A } T _J = 25 (125) °C	-	2,1(2,0)	-	V
V _{CEsat}	I _C = 900 A } T _J = 25 (125) °C	-	2,3(2,4)	-	V
I _{CETRIIP}	T _J = 125 °C, V _S = 15 V ± 0,6 V	≥ 1125	-	-	A
C _{CHC}	per SKiiPPACK AC side	-	2,4	-	nF
L _{CE}	Top (Bottom)	-	5	-	nH
t _{d(on)}	I _C = 900 A } V _{CC} = T _J = 125 °C } 300 V inductive load	-	120	-	ns
t _{d(on)Driver}		-	1,2	-	μs
t _r		-	200	-	ns
t _{d(off)}		-	0,4	-	μs
t _{d(off)Driver}		-	1,2	-	μs
t _f		-	850	-	ns
E _{on} + E _{off}	V _{CC} = 300 / 400 V	-	150/207	-	mJ

Inverse Diode ²⁾					
V _F = V _{EC}	I _F = 675 A } T _J = 25 (125) °C	-	1,5(1,5)	-	V
	I _F = 900 A } T _J = 25 (125) °C	-	1,7(1,7)	-	V
E _{on} + E _{off}	I _F = 900 A; T _J = 125 °C	-	27	-	mJ
IGBT / Inverse Diode ²⁾					
V _{TO}	T _J = 125 °C	-	0,9/0,74	-	V
r _T	T _J = 125 °C	-	1,7/1,1	-	mΩ
Thermal Characteristics					
R _{thjh}	per IGBT	-	0,053	-	K/W
R _{thjd}	per diode	-	0,09	-	K/W
T _{ip} ¹²⁾	Over temperature protection	109	115	121	°C
R _{thha} ⁶⁾	P16/280 F; v _{air} = 285 m ³ / h	-	0,036	-	K/W
Mechanical Data					
M _{dc}	for DC terminals, SI Units	4	-	6	Nm
Mac	for AC terminals, SI Units	8	-	10	Nm
Case			S3		

SKiiPPACK® SK integrated intelligent Power PACK halfbridge

**SKiiP 962 GB 060
+ Driver 350 WT/FT ⁷⁾**
Preliminary Data

Case S3



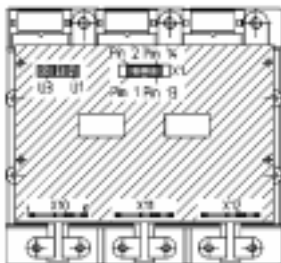
Features

- Low thermal impedance
- Optimal thermal management with integrated heatsink
- Pressure contact technology with increased power cycling capability, compact design
- Low stray inductance
- High power, small losses
- Overtemp. protection
- Short circuit protection
- Isolated power supply

- ¹⁾ T_{heatsink} = 25 °C, unless otherwise specified
- ²⁾ CAL = Controlled Axial Lifetime Technology (soft and fast) without driver
- ³⁾ Driver input to DC link/AC output or DC link/AC output to heatsink or other heatsink on request
- ⁴⁾ W - Driver wire input
F - Fiber optic input
T - Temperature protection
- ⁶⁾ AC connection busbars must be connected by user, copper busbars available on request
- ⁷⁾ 24 V supply voltage selective with SK-DC link (low inductance)
- ⁸⁾ thermal reference for R_{thjh}; R_{thha}

SKiPPACK®
SK integrated
intelligent Power PACK
halfbridge

SKiIP 962 GB 060
+ Driver 350 WT/FT ³⁾
Preliminary Driver Data



SKiIP 962 GB 060 - 350 WT/FT
Driver for Halfbridge

Absolute Maximum Ratings				
Symbol	Conditions	Values	Units	remark
V _{S1}	supply voltage primary	18	V	pin 8 / 9
V _{S2} ¹⁾	supply voltage primary	30	V	pin 6 / 7
I _{outmax}	output peak current max.	± 10	A	
I _{outAV}	output average current	± 100	mA	
f _{swmax}	switching frequency max.	11	kHz	
V _{CE}	collector emitter voltage sense across IGBT	600	V	
dv/dt	rate of rise and fall of voltage (secondary to primary side)	75	kV/μs	
V _{isol IO}	Isol. test volt. IN/OUT (RMS; 1 min)	2,5	kV~	
V _{isol 12}	Isol. test volt. output 1 - output 2	1,5	kV=	
T _{op} , T _{stg}	operating / stor. temperature	- 25 ... + 85	°C	WT-version
T _{op} , T _{stg}	operating / stor. temperature	0 ... + 70	°C	FT-version

Features

- CMOS compatible inputs
- Short circuit protection by V_{CE} monitoring and soft switch off
- Drive interlock top/bottom
- Isolation by transformers
- Supply undervoltage protection
- Overtemperature protection
- Fiber-optic connection (option)

- 1) 24 V - supply voltage selective
- 2) Open collector output, external pull-up resistor necessary
- 3) W - Driver wire input
F - Fiber optic input
T - Temperature protection

Characteristics				
Symbol	Conditions	Values	Units	remark
V _{S1}	supply voltage	15,0 ± 4 %	V	pin 8 / 9
V _{S2} ¹⁾	supply voltage	24,0 +20%/-15%	V	pin 6 / 7
V _{UVS}	supply voltage monitoring	13 / 19,5	V	15 V / 24 V
I _{SO1}	sup.current pr.side (standby)	200	mA	15 V supply
I _{SO2} ¹⁾	sup.current pr.side (standby)	160	mA	24 V supply
I _{S1}	sup. current pr.side (max)	680	mA	15 V supply
I _{S2} ¹⁾	sup. current pr.side (max)	530	mA	24 V supply
V _{IT+}	input thresh. volt. (high) min	12,9	V	
V _{IT-}	input thresh. volt. (low) max.	2,1	V	
V _{GE(on)}	turn-on output gate voltage	15	V	
V _{GE(off)}	turn-off output gate voltage	- 8	V	
t _{d(on)}	propagation delay time on	1,2	μs	typ.
t _{d(off)}	propagation delay time off	1,2	μs	typ.
t _{TD}	dead time of interlock	3	μs	typ.
V _{CEstat}	V _{CE} -thresh. st. monitoring	3,2	V	typ.
V _{ol} ²⁾	logic low output voltage	< 600	mV	15 mA
V _{oH} ²⁾	logic high output voltage	max. 30	V	
t _{pdon-error}	propag. delay time-on error	6	μs	typ.
t _{p RESET}	min. pulse width error memory RESET	5	μs	
T _{err}	max. temperature	115 ± 6	°C	
I _{AOmax}	max. output current	± 5	mA	pin 12